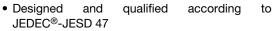


Thyristor High Voltage, Phase Control SCR, 50 A

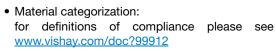


PRODUCT SUMMARY				
Package	TO-247L			
I _{T(AV)}	50 A			
V _{DRM} /V _{RRM}	1200 V			
V _{TM} (typ.)	1.1 V			
I _{GT} (typ.)	40 mA			
T _J max.	150 °C			
Diode variation	Single SCR			

FEATURES











HALOGEN

FREE

APPLICATIONS

Typical usage is in input rectification crowbar (soft start) and AC switch motor control, UPS, welding, and battery charge.

DESCRIPTION

The VS-50TPS12 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching, and phase control applications. The glass passivation technology used, has reliable operation up to 150 °C junction temperature.

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V _{RRM} /V _{DRM}		1200	V			
On-state voltage	V _T	50 A, T _J = 125 °C	1.1	V			
Average rectified forward current	I _{T(AV)}		50				
Maximum continuous RMS on-state current	I _{RMS}		79	Α			
Non-repetitive peak surge current	I _{TSM}		630				
Maximum rate of rise	dV/dt		1000	V/µs			
Operating junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C			

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA
VS-50TPS12L-M3	1200	1300	10



PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 112 °C, 180° conduction half sine wave		-	50	
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}			-	79	Α
Peak, one-cycle non-repetitive surge current	-	10 ms sine pulse, rated $V_{\mbox{\scriptsize RRM}}$ applied		-	530	
reak, one-cycle non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied	Initial $T_J = T_J$	-	630	
12t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	maximum	-	1405	A ² s
I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied		-	1986	
I ² √t for fusing	l²√t	$t = 0.1$ ms to 10 ms, no voltage reapplied, $T_J = 125$ °C		-	19 850	A²√s
Low level value of threshold voltage	V _{T(TO)1}	- T _J = 125 °C		-	0.89	V
High level value of threshold voltage	V _{T(TO)2}			-	0.97	v
Low level value of on-state slope resistance	r _{t1}			-	6.77	mΩ
High level value of on-state slope resistance	r _{t2}			-	6.32	
On state valtage	.,	50 A, T _J = 25 °C		1.2	1.32	V
On-state voltage	V _T	100 A, T _J = 25 °C			1.6	v
Rate of rise of turned-on current	dl/dt	T _J = 25 °C		-	150	A/µs
Holding current	I _H	Anode supply = 6 V, resistive load, T _J = 25 °C		-	300	
Latching current	IL			-	350	^
De conservat d'accel·lecture de conservat	I _{RRM} /I _{DRM}	T _J = 25 °C		-	0.05	mA
Reverse and direct leakage current		T _J = 125 °C		-	10	
Rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to 80 % V_{DRM} , R_q - $k = \infty \Omega$		-	1000	V/µs

TRIGGERING						
PARAMETER	SYMBOL		TEST CONDITIONS	TYP.	MAX.	UNITS
Peak gate power	P _{GM}	10 ma aina nula	o no voltage reapplied	-	10	W
Average gate power	P _{G(AV)}	10 ms sine puis	e, no voltage reapplied	-	2.5	VV
Peak gate current	I _{GM}			-	2.5	Α
Peak negative gate voltage	-V _{GM}			-	10	
		T _J = -40 °C	Anode supply = 6 V resistive load	-	1.6	V
Required DC gate voltage to trigger	V_{GT}	T _J = 25 °C		-	1.5	\ \
		T _J = 150 °C		-	1	
		T _J = -40 °C		-	160	
Required DC gate to trigger	I _{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	45	100	mA
		T _J = 150 °C		-	60	
DC gate voltage not to trigger	V_{GD}	T _J = 150 °C, V _{DBM} = rated value			0.2	٧
DC gate current not to trigger	I_{GD}	1J = 130 C, VD	RM = rateu value	-	3	mA

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS
Turn-on time	t _{gt}	$I_T = 50 \text{ A}, V_D = 50 \% V_{DRM}, I_{gt} = 300 \text{ mA}, T_J = 25 ^{\circ}\text{C}$	1.5	-	
Turn-off time	t _q	$I_{T} = 50 \text{ A, V}_{D} = 80 \% \text{ V}_{DRM}, \text{ dV/dt} = 20 \text{ V/}\mu\text{s, t}_{p} = 200 \mu\text{s}$ $I_{gt} = 100 \text{ mA, dI/dt} = 10 \text{ A/}\mu\text{s, V}_{R} = 100 \text{ V, T}_{J} = 150 \text{ °C}$	92	ı	μs



THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS	
Maximum junction and storage temp	erature range	T _J , T _{Stg}		-40	150	°C	
Maximum thermal resistance, junction to case		R_{thJC}		-	0.35		
Maximum thermal resistance, junction to ambient		R_{thJA}		-	40	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.2	-		
Mounting torque minimum maximum				6	(5)	kgf · cm	
				12	(10)	(lbf · in)	
Marking device			Case style Super TO-247L		50TPS12I	=	

ΔR_{thJ-HS} CONDUCTION PER JUNCTION											
DEVICE	S	SINE HALF-WAVE CONDUCTION RECTANGULAR WAVE CONDUCTION						UNITS			
DEVICE	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VS-50TPS12L-M3	0.143	0.166	0.208	0.299	0.490	0.099	0.168	0.223	0.311	0.494	°C/W

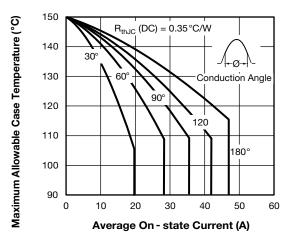


Fig. 1 - Current Rating Characteristics

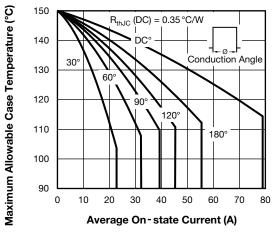


Fig. 2 - Current Rating Characteristics

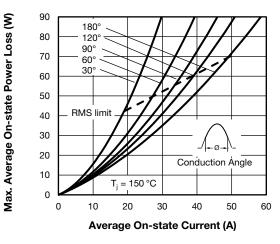


Fig. 3 - On-State Power Loss Characteristics

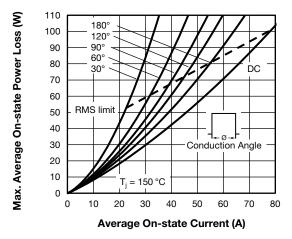


Fig. 4 - On-State Power Loss Characteristics



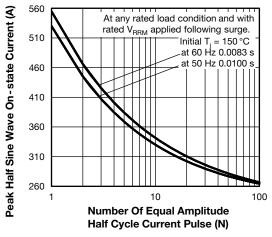


Fig. 5 - Maximum Non-Repetitive Surge Current

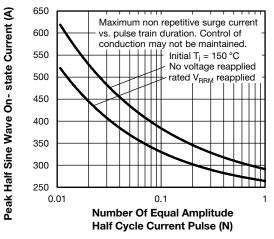


Fig. 6 - Maximum Non-Repetitive Surge Current

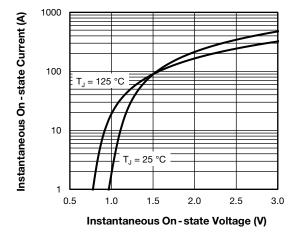


Fig. 7 - On-State Voltage Drop Characteristics

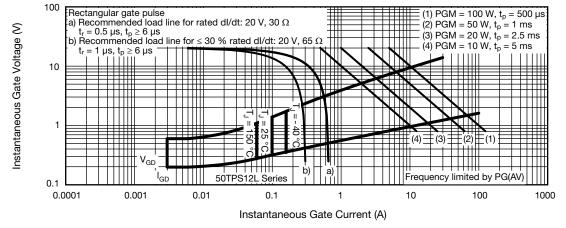


Fig. 8 - Gate Characteristics

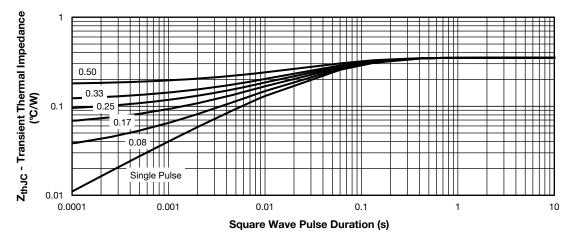
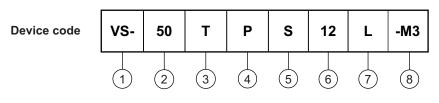


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE



- 1 Vishay Semiconductors product
- 2 Current code (50 = 50 A)
- **3** Circuit configuration:
 - T = thyristor
- 4 P = TO-247 package
- 5 Type of silicon:

S = standard recovery rectifier

- 6 Voltage code (12 = 1200 V)
- 7 Package L = long lead
- 8 -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-50TPS12L-M3	25	contact factory	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95626</u>					
Part marking information	www.vishay.com/doc?95007				



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Vishay

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